2SC4152

Silicon NPN triple diffusion planar type

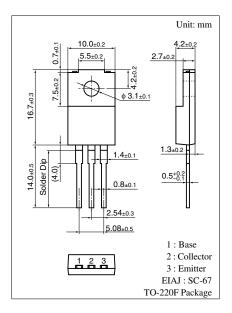
For high breakdown voltage high-speed switching

■ Features

- High-speed switching
- \bullet High collector to base voltage V_{CBO}
- Wide area of safe operation (ASO)
- ullet Satisfactory linearity of forward current transfer ratio h_{FE}
- Full-pack package which can be installed to the heat sink with one screw

■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter		Symbol	Rating	Unit
Collector to base voltage		V_{CBO}	1 400	V
Collector to emitter voltage		V _{CER}	1 400	V
		V _{CEO}	700	V
Emitter to base voltage		V_{EBO}	5	V
Peak collector current		I_{CP}	1.0	A
Collector current		I_C	0.3	A
Collector power	$T_C = 25^{\circ}C$	P_{C}	20	W
dissipation	$T_a = 25^{\circ}C$		2	
Junction temperature		T _j	150	°C
Storage temperature		T_{stg}	-55 to +150	°C

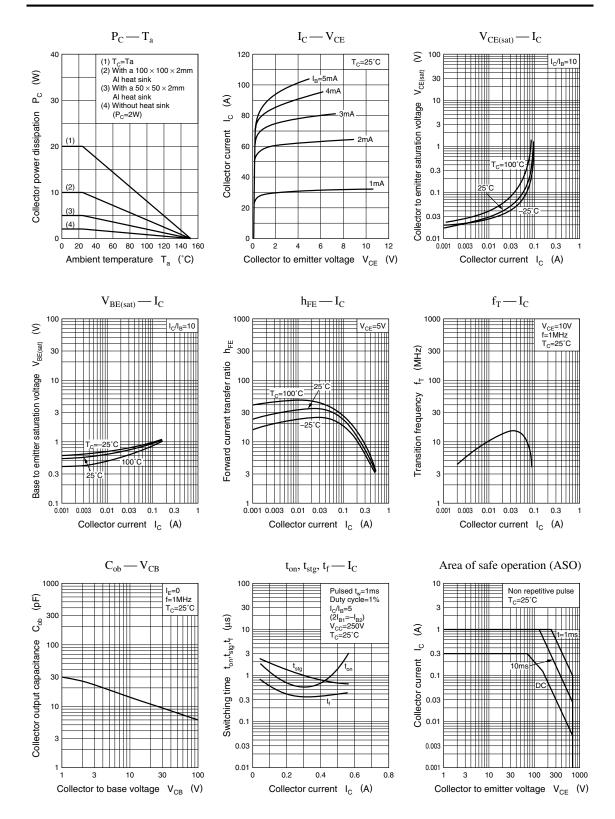


■ Electrical Characteristics $T_C = 25$ °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = 1\ 100\ V, I_E = 0$			10	μΑ
Emitter cutoff current	I_{EBO}	$V_{EB} = 4 \text{ V}, I_{C} = 0$			10	μΑ
Collector to emitter voltage	V _{CER}	$I_C = 1 \text{ mA}, R_{BE} = 100 \Omega$	1 400			V
	V _{CEO}	$I_{\rm C} = 1 \text{ mA}, I_{\rm B} = 0$	700			V
Emitter to base voltage	V_{EBO}	$I_E = 1 \text{ mA}, I_C = 0$	5			V
Forward current transfer ratio	h _{FE}	$V_{CE} = 5 \text{ V}, I_{C} = 30 \text{ mA}$	10		40	
Collector to emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = 60 \text{ mA}, I_{\rm B} = 6 \text{ mA}$			2	V
Base to emitter saturation voltage	V _{BE(sat)}	$I_{\rm C} = 60 \text{ mA}, I_{\rm B} = 6 \text{ mA}$			2	V
Transition frequency	f_T	$V_{CE} = 10 \text{ V}, I_{C} = 30 \text{ mA}, f = 1 \text{ MHz}$		12		MHz
Collector output capacitance	C _{ob}	$V_{CB} = 100 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		6		pF
Turn-on time	t _{on}	$I_C = 0.15 \text{ A}, I_{B1} = 15 \text{ mA}, I_{B2} = -30 \text{ mA},$			2	μs
Storage time	t _{stg}	$V_{CC} = 250 \text{ V}$			3	μs
Fall time	t_{f}				1	μs

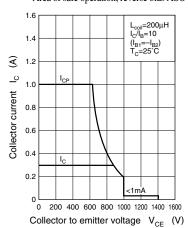
Panasonic 1

2SC4152 Power Transistors

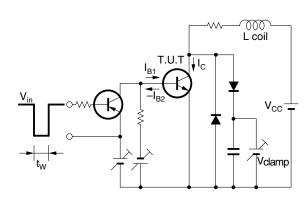


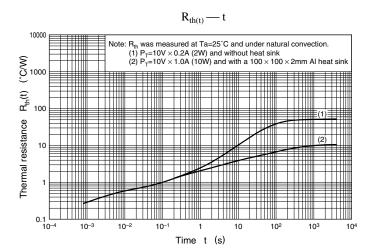
Power Transistors 2SC4152

Area of safe operation, reverse bias ASO



Reverse bias ASO measuring circuit





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